

Effect of pressure on the Fermi surface and electronic structure of ErGa_3

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The Fermi surface and cyclotron masses of the ErGa_3 compound are studied by means of the de Haas–van Alphen technique under pressure. Concurrently, the electronic structure is calculated *ab initio* for the ferromagnetic phase of ErGa_3 . The experimental data have been analyzed on the basis of the calculated volume-dependent band structure and compared with available results for isostructural TmGa_3 and LuGa_3 compounds.

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1. Introduction

The objective of the present work is a study of the pressure effect on the Fermi surface (FS) and cyclotron masses of the ErGa_3 compound by means of the de Haas–van Alphen (dHvA) effect. The pressure derivatives of dHvA frequencies and cyclotron masses are of particular interest due to their assumed sensitivity to details of the exchange interaction and many-body effects. Therefore, the present investigation can provide a critical test for recently developed methods of *ab initio* calculations of electronic and magnetic structures, and to stimulate the formulation of improved theories for rare-earths (RE).

This work represents an extension of our recent studies [1–3] of the FS and electronic structure in the cubic REGa_3 compounds at ambient pressure.

There are very little data available on the physical properties of ErGa_3 . The compound crystallizes in the AuCu_3 -type cubic structure and orders antiferromagnetically at $T_N = 2.8$ K by means of a continuous transition, and the corresponding magnetic structure is presumably the incommensurate modulated one [4]. It can be expected that at low temperatures ErGa_3 reveals large and field-dependent magnetization, in the same manner as is the case of TmGa_3 [2]. This provides a number of complications in the Fourier analysis of dHvA oscillations. Specifically, the dHvA effect has to be studied in sufficiently strong magnetic fields where magnetization is almost saturated. These fields are expected to be higher than the critical field destroying the antiferromagnetic order. By this means the dHvA effect can be investigated in a paramagnetic

phase of ErGa_3 , in which magnetic field leads to a quasi-ferromagnetic configuration of magnetic moments.

In the present work the experimental study of the dHvA effect under pressure is complemented by *ab initio* calculations of the spin-polarized electronic structure of ErGa_3 when the atomic volume is varied through a small range around the equilibrium value. Basically, the dHvA data supplemented by results of the calculations provide a possibility to estimate the volume dependencies of the FS and exchange interaction parameters, as well as the many-body enhancement of band cyclotron masses. A comparison of the data of the pressure effect and the calculated volume dependent band structure can be especially useful in testing the adequacy of theoretical models employed for rare-earth compounds. The evaluated parameters of the electronic structure of ErGa_3 are also compared with corresponding results obtained for the isostructural compounds TmGa_3 and LuGa_3 at ambient pressure [1,2].

2. Experimental techniques

Single crystals of ErGa_3 were grown by the flux method from the melt of the nominal composition 90% at. Ga and 10% at. Er. The purity of starting metals was 6N for Ga and 4N for Er. The feed placed in a alumina crucible and sealed in a quartz tube in argon atmosphere under pressure of 150 Torr at room temperature, was heated in a resistance furnace up to 920 °C, held at this temperature for 48 h and then slowly cooled down at the rate 0.8 K/h. The synthesis was stopped at about 350 °C and then sample was cooled rapidly down to room temperature for avoiding the formation of ErGa_6 in peritectic reaction [5]. The resulting crystals of ErGa_3 were immersed in an excess of Ga which is easy to remove. The obtained crystals had the form of cubes with maximum dimensions 5×5×5 mm. According to the x-ray examination the quality of single crystals was very good.

The dHvA effect measurements were performed on a spherical sample (diameter 2.5 mm) by using a standard field modulation technique at temperatures down to 1.5 K and in magnetic fields up to 15 T applied along principal crystallographic axes. Large amplitudes of the observed dHvA oscillations can be considered as another prove of the high quality of ErGa_3 single crystals. A standard Cu-Be clamp was used for the pressure effect study with an extracted benzene solvent as the medium transmitting pressure to the sample. The maximum pressure employed was 6.4 kbar at 4.2 K. A small manganin

coil with resistance about 60 Ω was placed near the sample to measure the applied pressure. Preliminary this coil has been trained to cooling-pressure and then calibrated by measuring the superconducting transition temperature of Sn [6]. A deviation of the manganin coil resistance due to the residual magnetic field of the superconducting magnet has been also taken into account. The sample, the pick-up coil, and the manganin coil, all were placed in a teflon cell, filled with the extracted benzene solvent, and then the cell was put in the pressure clamp. A deviation from hydrostatic pressure and its effect on the measurements are estimated to be negligible by observing that the superconducting transition width of Sn does not change noticeably and amplitudes of the dHvA oscillations do not decrease substantially under pressures used in this work.

Since the pressure clamp is heated with the modulation field, there is a difference in temperatures between the helium bath and the sample in the pressure clamp. The modulation amplitude and frequency used in measurements were 40 G and 38.5 Hz, respectively. These amplitude and frequency were chosen to produce a large enough dHvA signal, and, at the same time, to reduce the heating power, which leads to a temperature difference not exceeding 0.02 K.

In a magnetic material, the dHvA oscillations are periodic in B^{-1} , where B is the magnetic induction. For a spherical sample as we have used $\mathbf{B} = \mathbf{H}_{\text{appl}} + (8\pi/3)\mathbf{M}$, where \mathbf{H}_{appl} is the applied field and \mathbf{M} is the magnetization. Complementary magnetization measurements were performed by a home made vibrating sample magnetometer. The field dependence of the magnetization along the principal crystallographic axes is shown in Fig. 1. This dependence can be reproduced by a fitting calculation in the molecular-field approximation. The Hamiltonian employed contains the crystal field (CF), the exchange and Zeeman terms. The molecular-field exchange parameter was estimated, based on the value of the paramagnetic Curie temperature, $\Theta_p = -10$ K. Then the best fit to the experimental data was obtained for the CF parameters x and W (in the usual notations of Ref. [7]) equal to 0.22 and 0.25 K, respectively. This gives the Γ_7 doublet as the CF ground state, and the first excited state appeared to be the $\Gamma_8^{(1)}$ quartet at about 30 K. The total CF splitting is about 120 K. These parameters provided a possibility for evaluating the angular dependence of the magnetization [3].

The applied pressure modifies a magnitude and field dependence of the magnetization due to a

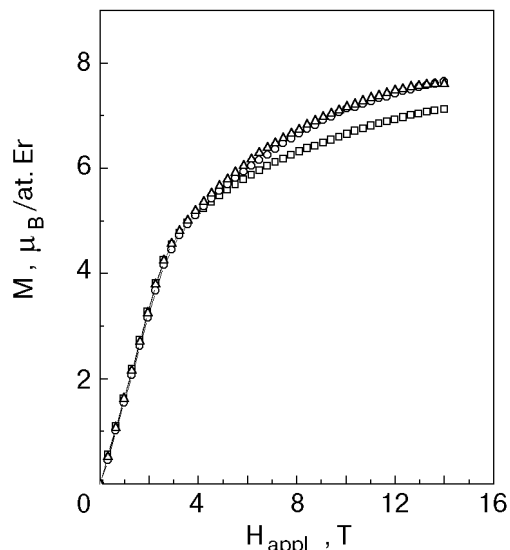


Fig. 1. Magnetization of ErGa_3 at 1.7 K in the magnetic field applied along $\langle 100 \rangle$ (\square), $\langle 110 \rangle$ (\circ), and $\langle 111 \rangle$ (Δ) axes.

pressure influence on the CF splitting, as well as on the exchange interaction. It is well known, that CF of metallic rare-earth compounds contains contributions from charges of surrounding ligands as well as from the direct Coulomb and exchange interactions of the rare-earth ion with conduction electrons. In order to estimate the influence of the pressure on the CF we have restricted ourselves to the contribution from surrounding ligands within the point charge model. The applied pressure P brings about the volume dilatation $\delta V/V = -P/c_B$, where c_B — bulk modulus. Under pressure of 10 kbar $\delta V/V$ is estimated to be -0.013 , when we assume for ErGa_3 the bulk modulus of TmGa_3 , equal to $c_B = 765$ kbar [8]. The change of CF due to this dilatation causes a variation of the magnetic induction at 1.7 K in the applied field of 15 T not larger than 20 G. One can estimate also a change of the magnetization in ErGa_3 due to a variation of the exchange interaction parameter under pressure by making use of appropriate data obtained for the isostructural REIn_3 compounds [9,10]. The corresponding variation of the magnetic induction with the applied pressure of 10 kbar is about -10 G at 1.7 K in the field of 15 T. Therefore, the total change of the magnetic induction reaches only 10 G, giving the relative variation of the dHvA frequency $\delta F/F \approx 2 \cdot 10^{-4} \text{ kbar}^{-1}$, which may be neglected in the Fourier analysis of the dHvA oscillations.

The dHvA effect measurements were carried out in magnetic fields higher than 8 T where the magnetization does not change appreciably and the Fourier analysis of the dHvA oscillations can be performed. In another case a dHvA frequency

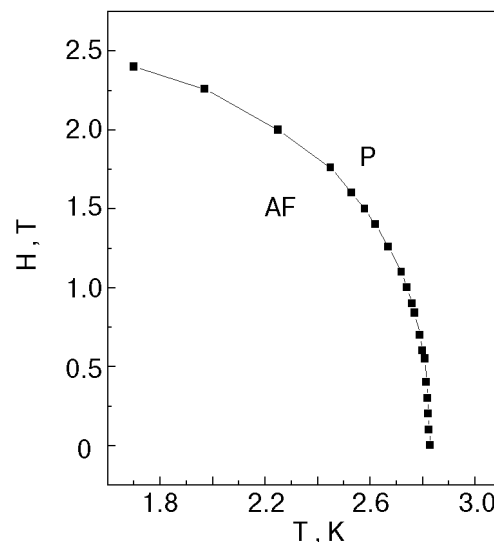


Fig. 2. Sketch of the magnetic phase diagram of ErGa_3 in the magnetic field applied along the $\langle 100 \rangle$ -axis. The curve is a line of phase transitions between an antiferromagnetic state and the paramagnetic one.

would change its value following the strength of external magnetic field. It turns out that for this intensity range ErGa_3 is in the paramagnetic state, and the measurements were carried out in this phase well above the antiferro-paramagnetic transition. Actually, along all principal crystallographic axes, $\langle 001 \rangle$, $\langle 011 \rangle$, and $\langle 111 \rangle$ the critical field of the antiferromagnetic — paramagnetic transition does not exceed 3 T. This is evident from a sketch of the magnetic phase diagram in Fig. 2, where the curve represents a transition between an antiferromagnetic state and the paramagnetic one for the fields applied along $\langle 100 \rangle$ axes. Actually, the magnetic phase diagram of ErGa_3 is more complex, and its full description, together with neutron diffraction data and the CF scheme examination, will be published elsewhere [11].

The magnetization in magnetic fields higher than 8 T tends to saturate and magnetic moments settle into a quasi-ferromagnetic configuration. Moreover, the magnetization along all directions in a magnetic field higher than 8 T appeared to be almost temperature independent in the range 1.7–4.2 K. Therefore, the evaluated values of the magnetization along the principal crystallographic axes were used in the Fourier analysis of dHvA oscillations. It should be pointed out that for the field induced quasi-ferromagnetic configuration the dHvA spectrum of ErGa_3 can be compared with results of band structure calculations for the corresponding spin-polarized state.

3. Details of calculations

At present it is commonly believed [12–14] that, within the local spin-density approximation (LSDA), a strict band treatment of the $4f$ states is inadequate for heavy rare earths. In the corresponding spin-polarized calculations the f -shell is not filled and the $4f$ bands, which act as a sink for electrons, always cut the Fermi level (E_F) leading to absurd values of specific heat coefficients [12] and wrong $4f$ occupancies, close to the divalent (i.e., atomic) configuration [15].

According to the photoemission data [15–17], the $4f$ spectral density for Er and Er-based compounds was observed about 5 eV below E_F . Therefore, for the present purpose, which is mainly to describe the band structure for the ground state near E_F , it seems reasonable to treat $4f$ states in ErGa_3 as semilocalized core states, in line with Refs. [10,13,14,18].

In fact, the standard rare-earth model [12] is employed in this work in the limit of the large Hubbard repulsion U within the *ab initio* LSDA scheme [19] for the exchange-correlation effects. The localized f -states of Er were treated as spin-polarized outer-core wave functions, contributing to the total spin density. Consequently, the spin occupation numbers were fixed by applying the Russell-Saunders coupling scheme to the $4f$ shell, which was not allowed to hybridize with conduction electrons.

The self-consistent band structure calculations were carried out for the paramagnetic configuration phase of ErGa_3 by using the linear muffin-tin orbital method (LMTO) in the atomic sphere approximation (ASA) with combined corrections to ASA included [20,21]. In the framework of the LSDA, the spin density of the $4f$ states polarizes the «spin-up» and «spin-down» conduction electron states through the local exchange interaction. The exchange split conduction electron states interact with the localized f states at other sites, appearing as the medium for the indirect f - f interaction [10,18].

In order to calculate FS orbits, the charge densities were obtained by including spin-orbit coupling at each variational step, as suggested in Refs. [12,13]. In this case the spin is no longer a good quantum number, and it is not possible to evaluate the electronic structure for «spin-up» and «spin-down» bands separately. Also, we have employed the approximation, which has been extremely successful for rare-earths [12], namely, to omit spin-orbit coupling in spin-polarized band structure calculations for ErGa_3 . It gives the possibility to

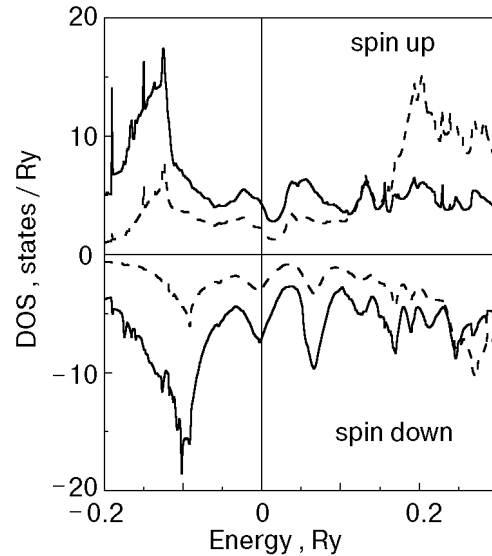


Fig. 3. Partial densities of states as a function of energy (relative to the Fermi energy E_F) for the ferromagnetic phase of ErGa_3 . Solid lines stand for p -states of Ga, and dashed lines represent d -states of Er.

elucidate the role of the spin-orbit coupling, and also to present «spin-up» and «spin-down» bands for field-induced ferromagnetic phase of ErGa_3 , where the exchange splitting is much larger than the spin-orbit coupling.

The band structure calculations were performed self-consistently on a uniform mesh of 455 points in the irreducible wedge of the cubic Brillouin zone for a number of lattice parameters close to the experimental one. The individual atomic radii of the components were chosen following the method outlined in Ref. [22].

The results obtained with the LMTO-ASA method were verified and supplemented by carrying out *ab initio* relativistic full-potential LMTO calculations of the electronic structure of ErGa_3 in an external magnetic field with the Zeeman term included (details of this method have been described elsewhere [23]). The calculated density of states (DOS) and band structure along selected high symmetry lines appeared to be similar in the two types of calculations.

The calculated partial densities of states for the ferromagnetic phase of ErGa_3 are presented in Fig. 3. Two fairly broad peaks, associated with bonding and antibonding states, originate due to hybridization of $5d$ -states of Er and $4p$ -states of Ga. As can be seen in Fig. 3, these p -states give substantial contribution to the total DOS at the Fermi energy. On the other hand, the exchange splitting is more pronounced for the $5d$ -states of Er (about 20 mRy) due to the local exchange interaction. For hybrid-

dized electronic states at E_F the exchange splitting takes smaller values, reducing to about 1 mRy for the pure p -states.

4. Results and discussion

The Fourier spectra of dHvA oscillations in ErGa_3 observed along $\langle 100 \rangle$ axis at different pressures are presented in Fig. 4, and the pressure effect on the corresponding dHvA frequencies is exhibited in Fig. 5. For all the principal crystallographic axes, $\langle 100 \rangle$, $\langle 110 \rangle$, and $\langle 111 \rangle$, the dHvA frequencies at ambient pressure and their pressure derivatives $d \ln F/dP$ are listed in Table 1.

Table 1

DHvA frequencies at ambient pressure, their pressure derivatives, and cyclotron effective masses at ambient pressure in ErGa_3

Field direction	F , MG	$d \ln F/dP$, 10^3 kbar^{-1}		m_c^* , m_0
	experiment	experiment	theory	experiment
$\langle 100 \rangle$	98.71	2.3 ± 0.3	1.3	0.96 ± 0.02
	97.81	1.4 ± 0.4	1.1	—
	41.07	1.7 ± 0.2	2.0	0.91 ± 0.02
	30.27	0.36 ± 0.02	—	0.92 ± 0.03
	12.66	-2.7 ± 0.1	-2.8	0.44 ± 0.02
	4.35	—	—	0.55 ± 0.02
	$\langle 110 \rangle$	96.03	1.2 ± 0.2	1.2
95.17		1.0 ± 0.3	1.1	—
15.80		-1.2 ± 0.1	—	—
15.14		-1.1 ± 0.1	—	0.57 ± 0.02
11.95		-2.4 ± 0.2	-2.0	0.84 ± 0.04
3.37		-4.5 ± 0.3	—	0.28 ± 0.02
$\langle 111 \rangle$		88.30	2.5 ± 0.3	1.4
	87.58	1.7 ± 0.1	1.2	—
	35.47	2.3 ± 0.2	1.9	0.70 ± 0.02
	4.21	—	—	0.51 ± 0.02

For reference, the angular dependence of dHvA frequencies in the $\langle 100 \rangle$ and $\langle 110 \rangle$ planes, obtained at ambient pressure in Ref. 3, is shown in Fig. 6. The intersections of the calculated FS of ErGa_3 with planes of the cubic Brillouin zone (Fig. 7) reveal the «spin-split» almost spherical electron FS centered at R -point and the complicated multiply connected hole FS centered at Γ - and X -points. As can be seen in Fig. 6, the agreement between the calculated FS and the experimental data is quite good in the range of the high dHvA frequencies (branch a which arise from the FS sheet at R -point, and branch d , associated with the largest sheet of the hole FS centered at Γ -point), as well as the medium ones (branch b , related to the hole FS sheet at X -point). Instead of the calculated branch j ,

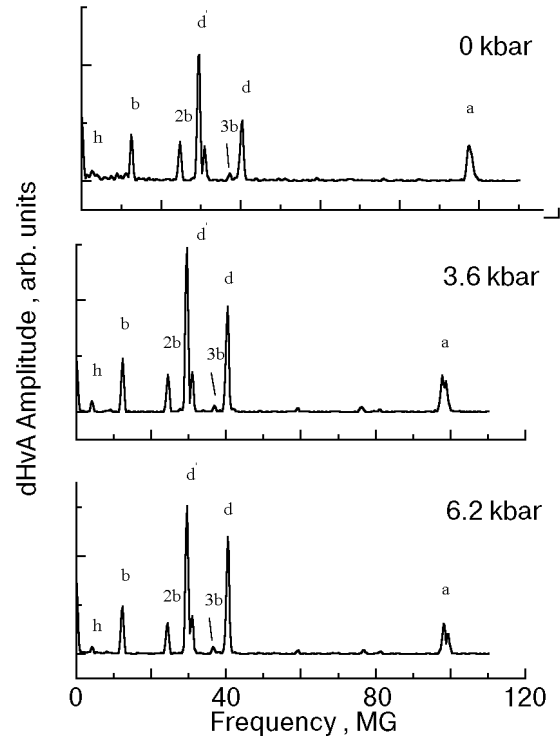


Fig. 4. Fourier spectra of dHvA oscillations observed at 2.1 K for magnetic fields directed along $[100]$ axis at ambient pressure, 3.6 kbar, and 6.2 kbar.

which arise from a «neck» at the symmetry line ΓR , a branch with a different angular field dependence has been observed in the range of low dHvA frequencies. It is analogous to the branch previously found in LuGa_3 [1], and labelled h in Fig. 6.

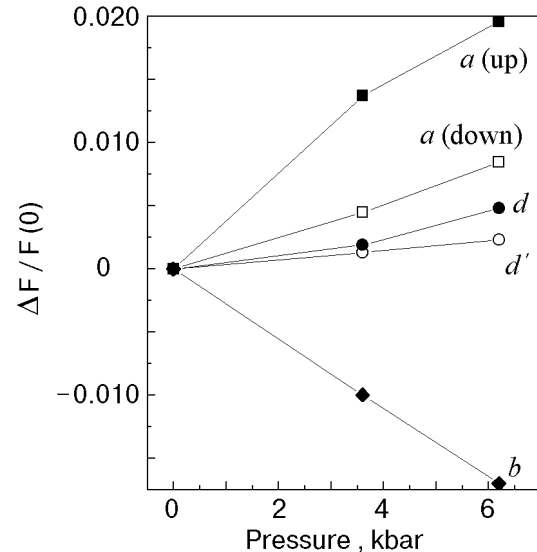


Fig. 5. Fractional changes of the dHvA frequencies, $\Delta F/F(0)$, as a function of pressure for the $[100]$ magnetic field direction at 2.1 K. The frequencies are labelled according to Ref.[3] and Fig. 6. The $a(\text{up})$ and $a(\text{down})$ refer to the oscillations originating from the «spin-up» and «spin-down» subbands of the a branch, respectively. The solid lines are guides for the eye.

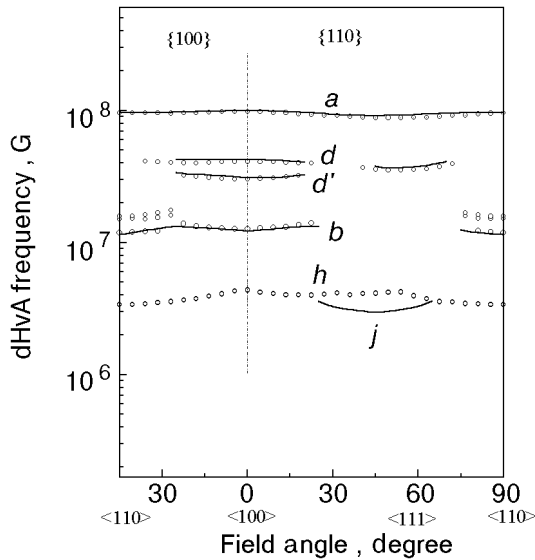


Fig. 6. Angular dependence of the dHvA frequencies in ErGa_3 , taken from Ref. [3]. Circles stand for the experimental data, solid lines show calculated results.

Basically, the dHvA spectrum of ErGa_3 in the field-induced ferromagnetic configuration appeared to be close to the spectrum of LuGa_3 [1], except for the presence of additional branch d' that is just below the d branch and located in the vicinity of the $\langle 100 \rangle$ axis. It should be pointed out that in a ferromagnetic configuration phase of the isostructural TmGa_3 compound the dHvA spectrum contains several h -like branches in the low frequency range and no d' -branch [2].

The dHvA oscillations originating from the «spin-split» subbands were observed only for the a branch. This splitting is seen in Fig. 4 and Fig. 5, but not resolved in Fig. 6 owing to the scale chosen. Based upon the calculated partial DOS in Fig. 3, one can expect the more easily observed dHvA

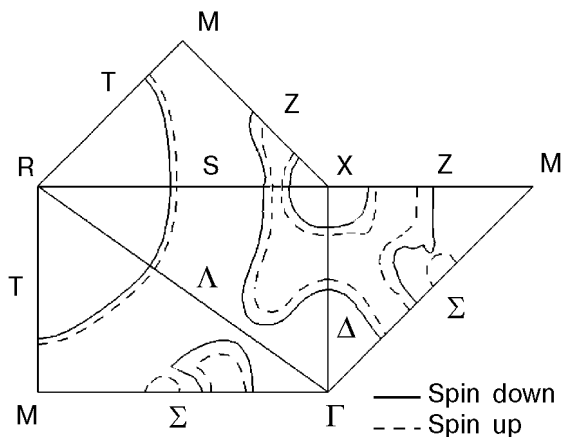


Fig. 7. Intersection of the Fermi surface for ErGa_3 with the Brillouin zone planes.

oscillations related to the majority states, having lower DOS and, correspondingly, lower band masses. In fact, the frequencies calculated for «spin-up» bands (which are actually presented in Fig. 6) appeared to be in better agreement with the experimentally observed ones.

The experimental pressure derivatives $d \ln F/dP$, presented in Table 1, are rather large in comparison with free-electron scaling prediction, which gives two-thirds the volume compressibility or $0.87 \cdot 10^{-3} \text{ kbar}^{-1}$, provided the available bulk modulus of TmGa_3 [8] is accepted for ErGa_3 . Basically, there is a qualitative agreement between the experimental and calculated $d \ln F/dP$ derivatives (again, the bulk modulus of TmGa_3 was used to convert the calculated volume derivatives to the pressure ones, listed in Table 1). The main discrepancy between these derivatives can be seen for the a branch, where the average exchange splitting is given by

$$\Delta E = 2\mu_B \Delta F(m_0/m_c^b),$$

where m_c^b is the calculated band cyclotron mass and m_0 is the free-electron mass. Taking into account the small value of this exchange splitting for the a branch (about 1 mRy), the difference between experimental pressure derivatives for the corresponding «spin-split» subbands can be considered as surprisingly large.

It was originally suggested in Ref. [24], that there are two contributions in ferromagnetic metals to the pressure derivative of dHvA frequency. The first («potential») contribution comes from an atomic volume effect on the crystal potential, and also from a scaling effect due to the change of the Brillouin zone size. It can be approximated by the corresponding derivative for a non-magnetic reference compound with a close value of the compressibility (in our case it can be LuGa_3). The second («magnetic») contribution originates from the redistribution of conduction electrons between spin-split subbands with pressure and the corresponding changes of volume enclosed by FS sheets. Within the Stoner–Wohlfarth model this contribution for ferromagnetic $3d$ -metals was described qualitatively by considering a pressure effect on the exchange splitting Δ [24]. According to the present calculations, Fermi surfaces of ErGa_3 do not change uniformly because of a strong \mathbf{k} -dependent p - d mixing effect on the exchange-split conduction band. As a result, the difference between pressure derivatives of the spin-split FS cross-sectional areas is inconsistent with prediction based on the Stoner–Wohlfarth model.

At this point, it is difficult to explain the discrepancy between the experimental and calculated derivatives of dHvA frequencies for the spin-split a branch in ErGa_3 . A detailed consideration of this problem should obtain further arguments in future planned experiments, which are aimed to reveal exchange-splitting for other FS sheets, as well as their pressure dependence. Also, a study of the dHvA effect under pressure in the reference non-magnetic compound LuGa_3 will provide a possibility to evaluate the «potential» contributions to the pressure derivatives for corresponding FS cross-sections of ErGa_3 . In addition, spin-polarized calculations of the volume-dependent FS with full-potential LMTO method will be helpful to clarify this problem. Compared to the LMTO-ASA method used for this purpose, a full-potential technique provides better description of electronic density in the interstitial region and, accordingly, more realistic p -like and p - d hybridized conduction electron states.

Cyclotron masses m_c^* have been determined at ambient pressure for all dHvA frequencies in the field applied along the $\langle 100 \rangle$, $\langle 110 \rangle$ and $\langle 111 \rangle$ axes, and appeared to be smaller than free electron mass (see Table 1). Also, the cyclotron masses measured at a pressure of 4 kbar for branches a and d in the field applied along the $\langle 111 \rangle$ axis are presented in Table 2. Band cyclotron masses m_c^b have been calculated for a and d branches, and are also given in Table 2.

The mass enhancement factor λ , which is defined by relation $m_c^* = m_c^b(1 + \lambda)$, presents a measure of interaction strength of conduction electrons with low energy excitations. The λ -factors for electrons on a and d orbits in ErGa_3 , TmGa_3 [2], and LuGa_3 [1,2] are listed in Table 2. In non-magnetic

LuGa_3 the λ -factor is presumably a measure of electron-phonon interactions, whereas in ErGa_3 and TmGa_3 this factor also contains contribution(s) coming from magnetic excitations. As seen in Table 2, in LuGa_3 the λ factor ranges from 0.3 (d branch) to about 1 (a branch). Assuming that values of $\lambda_{e\text{-ph}}$ in REGa_3 are close to the corresponding ones in LuGa_3 , one can estimate magnetic contributions λ_{mag} in ErGa_3 to be 0.4–0.6 and 0.4–0.7 for a and d orbits, respectively. In TmGa_3 the corresponding values of λ_{mag} are larger and more anisotropic, namely 0.5–1 and 0.8–1.5.

The hybridization of conduction electrons with $4f$ states could contribute to the large cyclotron masses observed in ErGa_3 (and TmGa_3), and affect the shape of FS as well. For heavy rare-earths these hybridization effects are commonly overestimated within LSDA, and corresponding calculations would lead to substantial reduction of the conduction band width in REGa_3 and, therefore, to remarkably different bulk properties in comparison to LuGa_3 . In accord with the lattice parameters behavior, which decrease slightly in a linear fashion in the series ErGa_3 , TmGa_3 , and LuGa_3 due to the lanthanide contraction, it can be expected, however, that conduction band widths are close in REGa_3 , and band cyclotron masses should be also close. At the present stage even calculations performed within LSDA+U or a Hubbard-like scheme would not be of decisive importance [14], and more elaborated analysis is necessary to estimate a scale of the hybridization effects.

One may assume that the distinctions between effective masses of TmGa_3 and ErGa_3 are most likely due to the different ground states 3H_6 and $^4I_{15/2}$ multiplets of Tm^{3+} and Er^{3+} ions in the CF of TmGa_3 and ErGa_3 , respectively. The CF scheme

Table 2

Cyclotron masses (experimental, m_c^* , and calculated, m_c^b , in units of free-electron mass) and the corresponding mass enhancement factor λ in REGa_3 compounds at ambient pressure. For ErGa_3 , two effective masses measured at 4 kbar are also presented

Branch and orientation	ErGa_3				TmGa_3^a			LuGa_3^a		
	m_c^*	m_c^* , 4 kbar	m_c^b	λ	m_c^*	m_c^b	λ	m_c^*	m_c^b	λ
a , $\langle 100 \rangle$	0.96 ± 0.02	—	0.40	1.4	1.20 ± 0.02	0.41	1.93	0.74 ± 0.02	0.38	0.95
a , $\langle 110 \rangle$	0.89 ± 0.02	—	0.37	1.4	1.02 ± 0.03	0.38	1.68	0.73 ± 0.02	0.36	1.03
a , $\langle 111 \rangle$	0.80 ± 0.02	0.94 ± 0.03	0.37	1.16	0.77 ± 0.02	0.38	1.03	0.57 ± 0.02	0.36	0.58
d , $\langle 100 \rangle$	0.91 ± 0.02	—	0.46	0.98	1.30 ± 0.02	0.46	1.83	0.63 ± 0.02	0.48	0.31
d , $\langle 111 \rangle$	0.70 ± 0.02	0.92 ± 0.03	0.40	0.75	0.90 ± 0.02	0.42	1.14	0.53 ± 0.02	0.39	0.36

^a Taken from Ref. [2]

of TmGa_3 provides the triplet $\Gamma_5^{(1)}$ as the ground state with intrinsic magnetic and quadrupolar moments [8]. Therefore, in TmGa_3 the enhancement factor λ presumably contains a contribution from coupled magnetic-quadrupolar excitations. Also, in the quasi-ferromagnetic configuration of magnetic moments, the exchange splitting of conduction bands can vary in ErGa_3 and TmGa_3 due to the difference in corresponding $4f$ -shell spin occupation numbers. At the moment one cannot attribute the differences in cyclotron masses (and angular dependencies of dHvA frequencies as well) in an unambiguous way in ErGa_3 and TmGa_3 either to the conduction band splitting or the magnetostriction.

In addition, one more mechanism can govern these differences. Namely, it was shown in Ref. [25] that virtual magnetic excitations can contribute substantially to the effective mass of the conduction electrons in rare-earth systems. These excitations are magnetic excitons in a paramagnetic system (e.g., praseodymium), and spin waves in magnetically ordered rare-earths. The mass enhancement appeared to be large, magnetic field dependent, and proportional to the static susceptibility of magnetic system. According to estimations of the electronic specific-heat coefficients, performed in Ref. [25], the corresponding effective masses increase in the series of heavy rare-earth metals. This trend correlates with the observed cyclotron masses in ErGa_3 and TmGa_3 , but considerable work is needed to employ the theory developed in Ref. [25] for a quantitative description of cyclotron masses in magnetic REGa_3 compounds. In this connection the results [26] of the dHvA effect studies at ambient pressure in isostructural REIn_3 compounds, which possess similar FS's, should be taken into consideration as well.

Summary

As a whole, the calculated pressure derivatives of the dHvA frequencies in ErGa_3 appeared to be in agreement with the experimental ones although the nature of some discrepancies is not clear. In particular, the difference between pressure derivatives of the spin-split FS cross-sectional areas is inconsistent with estimations based on the Stoner–Wohlfarth model, as well as with the results of *ab initio* LSDA calculations. Also, a surprisingly large and intriguing pressure effect on cyclotron masses has been observed in ErGa_3 , which cannot be explained within the standard rare-earth model employed. It has to be emphasized that different interactions (exchange splitting, CF and magnetic-quadrupolar

excitations, spin waves) have to be taken into account in a further theoretical analysis of the revealed pressure effects on the FS and cyclotron masses. In addition, more experimental data on the pressure dependence of the dHvA frequencies and cyclotron masses in REGa_3 and REIn_3 compounds are much needed to elucidate the nature of these effects.

The authors dedicate this work to the 80th anniversary of B. I. Verkin, who was a pioneer of the dHvA effect studies under pressure [27].

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